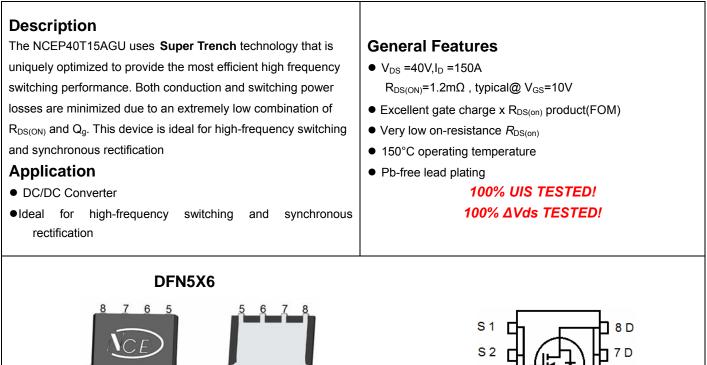
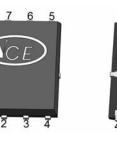
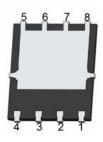


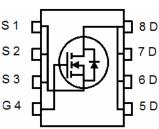
NCE N-Channel Super Trench Power MOSFET







Bottom View



Schematic Diagram

Package Marking and Ordering Information

Top View

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P40T15AGU	NCEP40T15AGU	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (T_c=25[°]Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	40	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous (Silicon Limited)	Ι _D	150	А
Drain Current-Continuous(Tc=100℃)	I _D (100℃)	106	A
Pulsed Drain Current (Package Limited)	I _{DM}	400	A
Maximum Power Dissipation	PD	135	W
Derating factor		1.1	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	1620	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{θJC}	0.93	°C/W]
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Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	· ·					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	40		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	· · · ·		-			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =75A	-	1.2	1.5	mΩ
Gate resistance	R _G	F=1.0MHz	-	2.5	-	Ω
Forward Transconductance	g fs	V_{DS} =5V,I _D =75A		80	-	S
Dynamic Characteristics (Note4)	· · · ·		-			
Input Capacitance	C _{Iss}	V _{DS} =20V,V _{GS} =0V,	-	4000	-	PF
Output Capacitance	C _{oss}		-	2110	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	100	-	PF
Switching Characteristics (Note 4)	· ·					
Turn-on Delay Time	t _{d(on)}		-	9	-	nS
Turn-on Rise Time	tr	V _{DD} =20V,I _D =75A	-	6	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =1.6 Ω	-	38	-	nS
Turn-Off Fall Time	t _f		-	6	-	nS
Total Gate Charge	Qg	V	-	62	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =20V,I _D =75A,	-	19.7	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	14.4	-	nC
Drain-Source Diode Characteristics	i		-			·
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =75A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	150	А
Reverse Recovery Time	t _{rr}	T_J = 25°C, I_F = I_S	-		30	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-		110	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

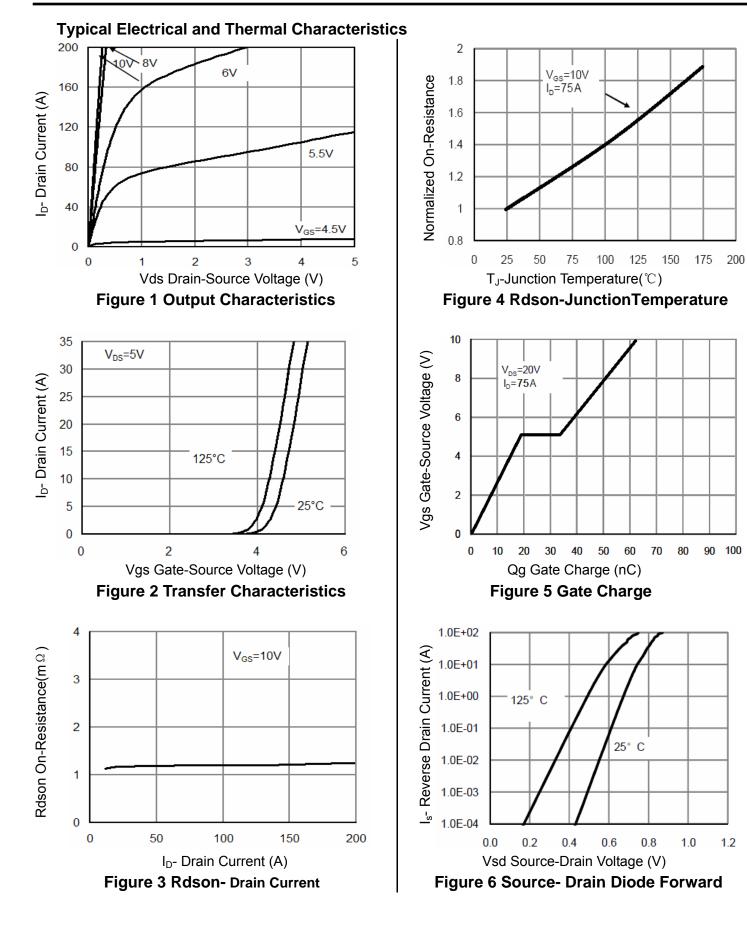
3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ \!\! \mathbb{C}$,V_DD=20V,V_G=10V,L=0.5mH,Rg=25 $\!\Omega$



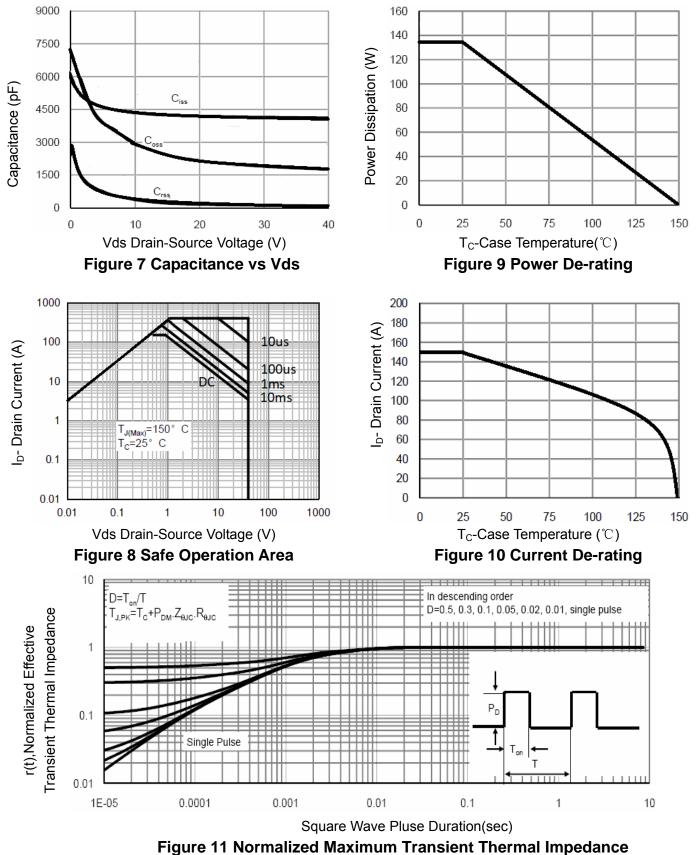
http://www.ncepower.com





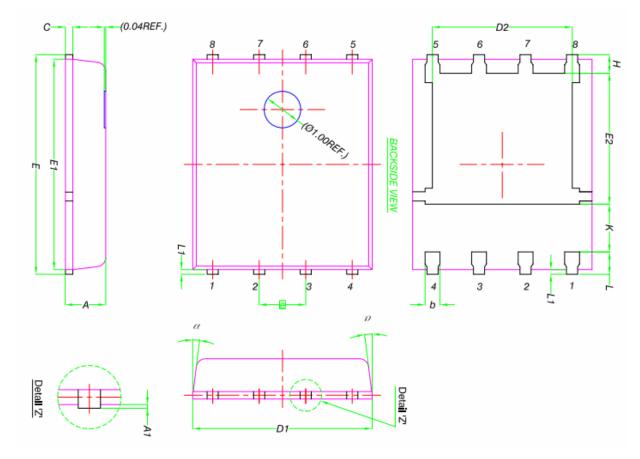
http://www.ncepower.com

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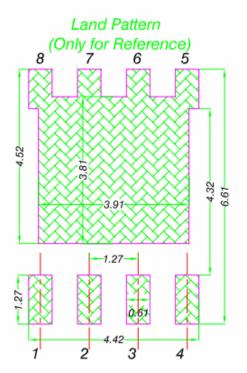




DFN5X6-8L Package Information



	MILLIMETERS			
DIM.	MIN.	NOM.	MAX.	
Α	0.90	1.00	1.10	
A1	0	-	0.05	
b	0.33	0.41	0.51	
С	0.20	0.25	0.30	
D1	4.80	4.90	5.00	
D2	3.61	3.81	3.96	
E	5.90	6.00	6.10	
E1	5.70	5.75	5.80	
E2	3.38	3.58	3.78	
е	1.27 BSC			
Н	0.41	0.51	0.61	
к	1.10	-	-	
L	0.51	0.61	0.71	
L1	0.06	0.13	0.20	
α	0°	-	12°	





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